Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-372-1816

Inclosu	re Material:
Plastic a	all transistor
Overall	Length:
0.170 in	ches all transistor and 0.210 inches all transistor
Termina	al Length:
0.500 in	ches all transistor
Internal	Configuration:
Field eff	ect all transistor
Channe	el Polarity And Control Type (non-core):
N-chanr	nel junction type all transistor
Joint El	lectronic Device Engineering Council/jedec/case Outline Designation:
To-92 al	Il transistor
Compo	nent Function Relationship:
Matcheo	t de la construcción de la const
Compo	nent Name And Quantity:
2 transis	stor
Mountir	ng Method:
Termina	al all transistor
Semico	nductor Material:
Silicon a	all transistor
Voltage	Rating In Volts Per Characteristic:
25.0 bre	eakdown voltage, gate-to-source, with all other terminals short-circuited to source all transisto
Current	Rating Per Characteristic:
9.00 mil	liamperes zero-gate-voltage source current megawatts all transistor
Termina	al Type And Quantity:
3 uninsu	ulated wire lead all transistor
Shelf Li	ife:
N/a	
Unit Of	Measure:
Demilita	arization:
No	
Fiig:	